# Layer Thickness Dependence of Spin Orbit Torques and Fields in Pt/Co/AlO Trilayer Structures.

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## Abstract

We measure the strength of two torques of even and odd symmetry via spin orbit interaction in Pt/Co/AlO with varying Pt thicknesses. Torque strength was measured by the effective field on the magnetization through an AC magnetization tilting technique. The even torque term is found to be stronger for increasing Pt thickness and closely related to the spin Hall effect and the bulk Pt layer. The odd torque is smaller than the even torque and exists for thin Pt thicknesses indicating its relation to the interface of Pt/Co.

## Introduction

Magnetization control via spin orbit interaction [1][2] (SOI) in Pt/Co/AlO [3-5] and other similar trilayer structures have been attributed to the spin Hall effect [6-11] (SHE) as well as the Rashba effect [3-5][12-16]. It can be ascertained that through Rashba, and SHE there exists two distinct torques of odd and even symmetry [17] respectively about the magnetization. The even torque ( $\tau_{even}$ ) arising from the angular momentum exertion from a spin current [18][19] applied to the magnetization is represented by

$$\tau_{\text{even}} = \frac{I_{\text{S}}\hbar}{2e} (\widehat{\mathbf{m}} \times \widehat{\boldsymbol{\sigma}} \times \widehat{\mathbf{m}}) \propto (\widehat{\mathbf{m}} \times \widehat{\mathbf{y}} \times \widehat{\mathbf{m}}) \quad (1)$$

where  $I_s$  is the spin current, m is the magnetization unit vector and  $\sigma$  is the spin unit vector. The odd torque resulting from the exchange interaction from a spin orbit coupled conduction electron and the local magnetization is given by

$$\tau_{odd} = \vec{H} \times \vec{M}, \qquad \vec{H} = \frac{\alpha_{R}}{\mu_{B}M} J(\hat{z} \times \vec{J_{e}})$$

$$\tau \propto (\hat{y} \times \hat{m})$$
(2)

where  $\alpha_R$  is the Rashba or spin orbit parameter, J is an exchange coupling constant M is the saturation magnetization and  $\mu_B$  is the Bohr magneton. Even and oddness is established by the order of magnetization vector product in eq. (1), (2). A further distinction between the  $\tau_{odd}$  and  $\tau_{even}$  is the physical origins stemming from bulk or interfacial aspects of the film which can be examined by varying thicknesses. In the present experiment, we attempt to measure the strength of the  $\tau_{even}$  and  $\tau_{odd}$  on the magnetization of Pt/Co/AlO in terms of an effective field  $H_L$  and  $H_T$  respectively by an

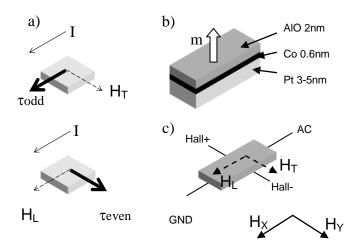


Fig 1. (a) orientations of  $\tau_{odd}$  and  $\tau_{even}$  and the associated field  $H_T$ ,  $H_L$  orientations with respect to current. (b) the stack structure of Pt/Co/AlO with perpendicular magnetization. (c) Device configuration.  $H_{XY}$  are the orientations of the externally applied field.

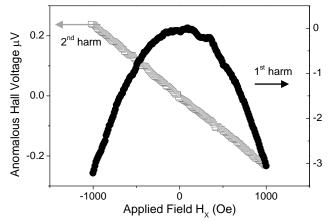


Fig 2. 1<sup>st</sup> and 2<sup>nd</sup> harmonic signals for Pt<sub>3</sub>/Co/AlO measured with an external applied field in the x direction H<sub>x</sub>. The 2<sup>nd</sup> harmonic signal was measured with a current amplitude of  $10^8$  A/cm<sup>2</sup> and a current amplitude of  $5 \times 10^7$  A/cm<sup>2</sup> was used for the 1<sup>st</sup> harmonic.

AC induced magnetization tilting technique with several films of varying thickness [20].

#### Experiment

Pt, Co and AlO layers (bottom to top) were deposited onto an MgO (111) substrate through RF magnetron sputtering and shaped into 5  $\mu$ m by 50  $\mu$ m rectangles. Layer thicknesses were selected to be Pt 5 nm / Co 0.6 nm /AlO 2nm (Pt<sub>5</sub>Co/AlO) and Pt 3 nm / Co

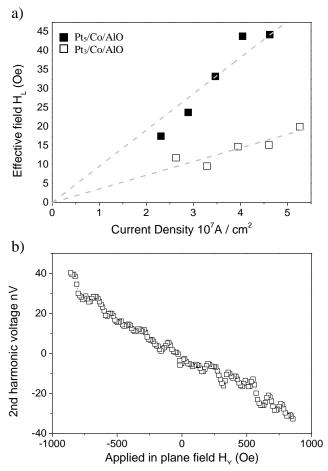


Fig 3. (a) comparison of the strength of the effective field  $H_L$  against the current amplitude. Values in tbl. 1 are calculated through the linear fit. (b) the 2<sup>nd</sup> harmonic signal of  $H_T$ . The strength of HT is significantly smaller than HL and exists only for Pt<sub>3</sub>/Co/AlO.

	HL	H <sub>T</sub>
Pt <sub>3</sub> /Co/AIO	45	11
Pt <sub>5</sub> /Co/AIO	115	None detected

Tbl. 1. Values of the effective field measured for  $H_L$  and  $H_T$  for the samples with units of Oe cm<sup>2</sup> / 10<sup>8</sup> A.

0.6 nm / AlO 2 nm (Pt<sub>3</sub>/Co/AlO). An AC current was applied longitudinally while the hall voltage was measured transversely Fig. 1c. The hall voltage signal contains a first harmonic signal corresponding to the AC current induced anomalous Hall voltage and a second harmonic component accounting for the tilting of the magnetization by  $H_L$  or  $H_T$ . To obtain the strength of  $H_{L(T)}$ , the 1<sup>st</sup> and 2<sup>nd</sup> harmonic hall voltages are measured by a lock in amplifier and an applied magnetic field  $H_{x,(y)}$  is swept in the x (y) direction. The strength of  $H_{L,(T)}$  can be given by [20]

$$H_{L(T)} = 2 \frac{\partial V_{2\omega} / \partial H_{X(Y)}}{\partial^2 V_{\omega} / \partial H_{X(Y)}^2}$$
(3)

# Discussion

For both samples, linear  $2^{nd}$  harmonic signal are observed for an applied field swept in the x direction which are then linearly fitted to determine the

 $(\partial V_{2\omega}/\partial H_X)$ . Parabolic 1<sup>st</sup> harmonic are observed and fitted with a second order polynomial function to determine  $\partial^2 V_{\omega} / \partial H^2_{X(Y)}$  from which  $H_L$  can be determined. Through several applied AC currents, it is determined that the longitudinal field H<sub>L</sub> (associated with  $\tau_{even}$ ) is linear to the applied current and strongest at 115 Oe  $\text{cm}^2/10^8\text{A}$  for Pt<sub>5</sub>/Co/AlO and 45 Oe  $\text{cm}^2/10^8\text{A}$ Pt<sub>3</sub>/Co/AlO Fig. 3. The lower H<sub>L</sub> found in Pt<sub>3</sub>/Co/AlO compared to Pt5/Co/AlO can be explained by the suppression of spin current generation by the spin Hall effect in Pt as the thickness approaches the spin diffusion length of 1.4 nm in Pt[9]. This affirms that  $\tau_{even}$ measured by H<sub>L</sub> is largely due to the spin Hall effect which is related to the bulk structure of the Pt layer and diminishes with decreasing Pt thickness. In Pt<sub>3</sub>/Co/AlO, a transverse field  $H_{T}$  associated with  $\tau_{odd}$  is detectable with an applied AC current of  $1.2 \ 10^8 \ \text{A/cm}^2$  while no noticeable field is detected for Pt5/Co/AlO. The lack of H<sub>T</sub> in Pt<sub>5</sub>/Co/AlO layers is likely due to the current shunting from the Co and inhibiting any spin orbit torques associated with the Pt/Co interface. In addition to the two torques distinction with magnetization symmetry, the results also indicate that there is also a distinction between bulk and interface effects as well.

#### Conclusion

We measured the  $H_T$  attributed to the Rashba effect and  $\tau_{odd}$ , as well as  $H_L$  attributed to the spin Hall torque and  $\tau_{even}$ .  $H_L$  is strongest in Pt<sub>5</sub>/Co/AlO approximately 115 Oe cm<sup>2</sup>/10<sup>8</sup>A and in 45 Oe cm<sup>2</sup>/10<sup>8</sup>A Pt<sub>3</sub>/Co/AlO. HT attributed to the Rashba effect and found to be Oe cm<sup>2</sup>/10<sup>8</sup>A in Pt<sub>3</sub>/Co/AlO at nonexistent in Pt<sub>5</sub>/Co/AlO. We find that the  $H_L$  is related to the bulk structure of Pt while  $H_T$  originates from the interface between the Pt/Co. Additional measurements in varying thickness will be carried out to further examine these two torques and fields.

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